

GTM CORPORATION

ISSUED DATE :2004/05/24
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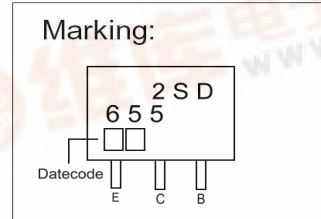
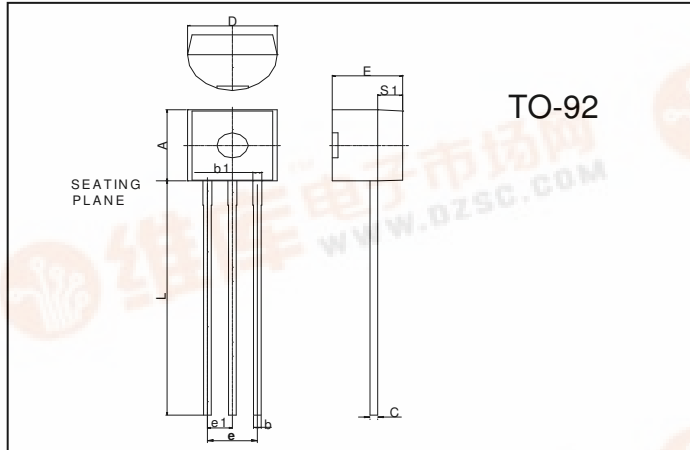
G2SD655

Silicon NPN Epitaxial

Application

Low frequency power amplifier, Muting.

Package Dimensions



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	4.45	4.7	D	4.44	4.7
S1	1.02	-	E	3.30	3.81
b	0.36	0.51	L	12.70	-
b1	0.36	0.76	e1	1.150	1.390
C	0.36	0.51	e	2.42	2.66

Absolute Maximum Ratings (Ta = 25°C)

Parameter		Ratings	Unit
Collector to Base Voltage	VCBO	30	V
Collector to Emitter Voltage	VCEO	15	V
Emitter to Base Voltage	VEBO	5	V
Collect Current(DC)	IC	0.7	A
Collect peak current	IC(peak)	1.0	A
Junction Temperature	Tj	+150	°C
Storage Temperature Range	Tstg	-55 ~ +150	°C
Total Power Dissipation	Pd	500	mW

Electrical Characteristics(Ta = 25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BVCBO	30	-	-	V	IC=10uA, IE=0
BVCEO	15	-	-	V	IC=1mA, RBE=∞
BVEBO	5	-	-	V	IE=10uA, IC=0
ICBO	-	-	1.0	uA	VCB=20V, IE=0
VBE	-	-	1.0	V	VCE=1V, IC=150mA
VCE(sat)	-	0.15	0.5	V	IC=500mA, IB=50mA *2
hFE1 *1	250	-	1200		VCE=1V, IC=150mA *2
fT	-	250	-	MHz	VCE=1V, IC=150mA

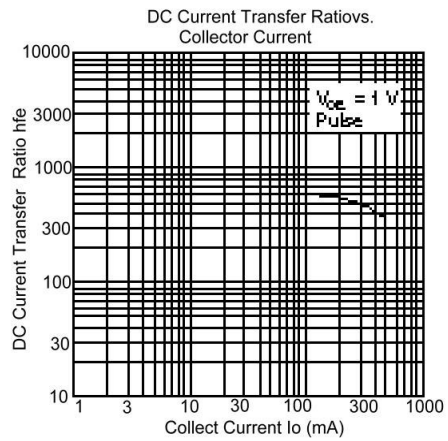
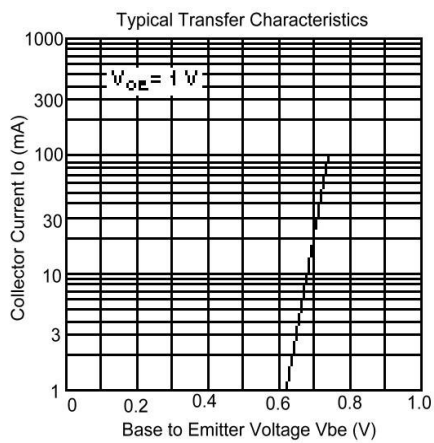
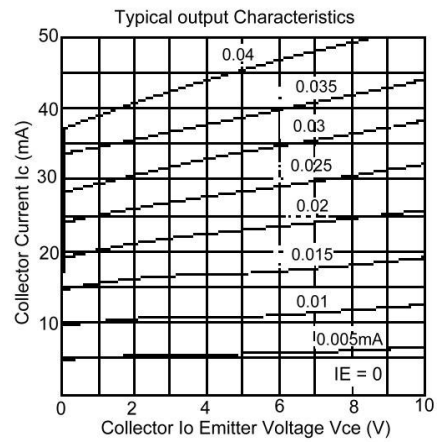
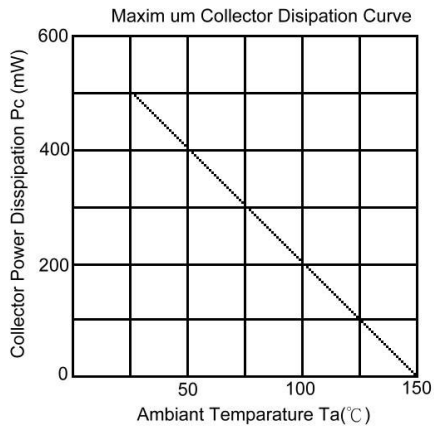
Notes: 1. The G2SD655 is grouped by hFE as follows.

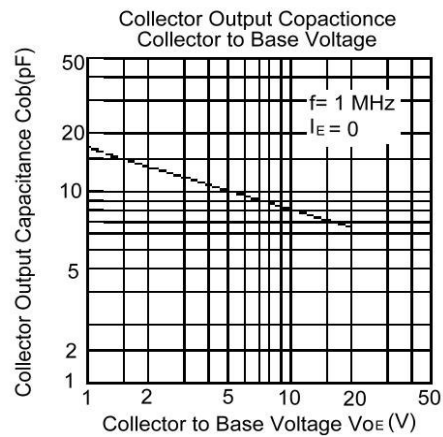
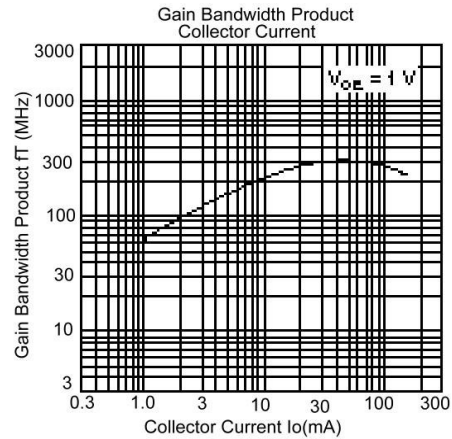
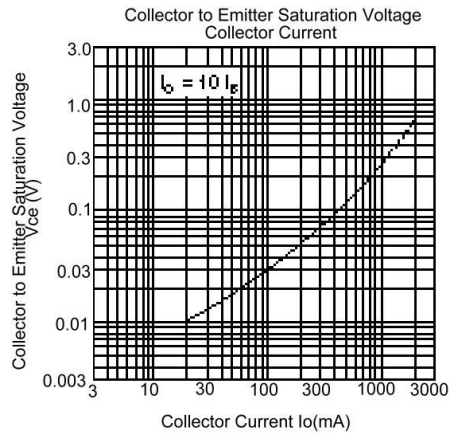
2. Pulse test

Classification of Rank

Rank	D	E	F
Range	250-500	400-800	600-1200

Characteristics Curve





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